PNP/NPN Epitaxial Planar Silicon Transistors

2SA1606/2SC4159



High-Voltage Switching, AF 100W Driver Applications

Applications

· High-voltage switching, AF power amplifier, 100Wunit:mm output predrivers.

Features

 \cdot Micaless package facilitating mounting.

Package Dimensions



():2SA1606

Specifications

Absolute Maximum Ratings $at Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V		(–)180	V
Collector-to-Emitter Voltage	СВО		(–)160	V
Emitter-to-Base Voltage	CEO		(–)6	V
Collector Current	V		(-)1.5	А
Collector Current (Pulse)	EBO		(–)3	А
Collector Dissipation	С	Tc=25°C	15	W
Junction Temperature	I		150	0
Storage Temperature	CP P		-55 to +150	C

Electrical Characteristics at $Ta = 25^{\circ}_{C}C$

	IJ					U
Parameter	Tstg	Conditions		Ratings		
	Gymbor		min	typ	max	
Collector Cutoff Current	I	V			(–)10	t µA
Emitter Cutoff Current	СВО	CB=(-)120V, IE=0			(–)10	μΑ
DC Current Gain	EBO	EB=(-)4V, IC=0	60*		200*	
Gain-Bandwidth Product	h	V		100		MHz
Output Capacitance	FE	CE=(-)5V, IC=(-)300mA		(30)23		pF
Base-to-Emitter Voltage	f T	V CE=(-)10V, IC=(-)50mA		~ .	(–)1.5	V
* : The 2SA1606/2SC4159 are classified by 300mA h _{FE} at follows :					ued on ne	ext page.
	ch	$CP_{(1)}(10)/f_{10}MU_{7}$				

60 D 120 100 E 200

V BE

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CB=(-)10V, f=1MHz V CE=(-)5V, IC=(-)10mA

Continued from preceding page.

Parameter		Symbol Conditions	Ratings			Unit
			min	typ	max	0.110
Collector-to-Emitter Saturation Voltage	V			(-0.5)		V
	CE(sat) IC=(-)500mA, IB=(–)50mA		0.3		V
Collector-to-Base Breakdown Voltage	V		(–)180			V
Collector-to-Emitter Breakdown Voltage	(BR)CBO IC=	(–)1mA, IE=0	(–)160			V
Emitter-to-Base Breakdown Votage	V		(–)6			V
Turn-ON Time	+ (BR)CEO IC=	(–)1mA, RBE=∞		(0.29)		μs
	(BR)EBO IE=	(–)1mA, IC=0		0.15		μs
Fall Time	t			(0.19)		μs
	on See spec	lified test circuit.		0.48		μs
Storage Time	See specifie	p test circuit.		(0.48)		μs
-	F See specif	ed test circuit.		0.81		μs
	See specifie	d test circuit.				

Switching Time Test Circuit



tstg See specified test circuit.

-2V 20V 10IB1=-10IB2=IC=0.5A PW=20μs For PNP, the polarity is reversed. Unit (resistance : Ω, capacitance : F)



No.2535-2/4

2SA1606/2SC4159



No.2535-3/4

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